

# アモルファス材料中の イオン移動挙動解析のための ニューラルネットワーク 原子間ポテンシャルの開発

東大院工 マテリアル工学専攻

NIMS 統合型材料開発・情報基盤部門 情報統合型物質・材料研究拠点

渡邊聡

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# Atom/ion diffusion

Important roles in novel nano-scale devices

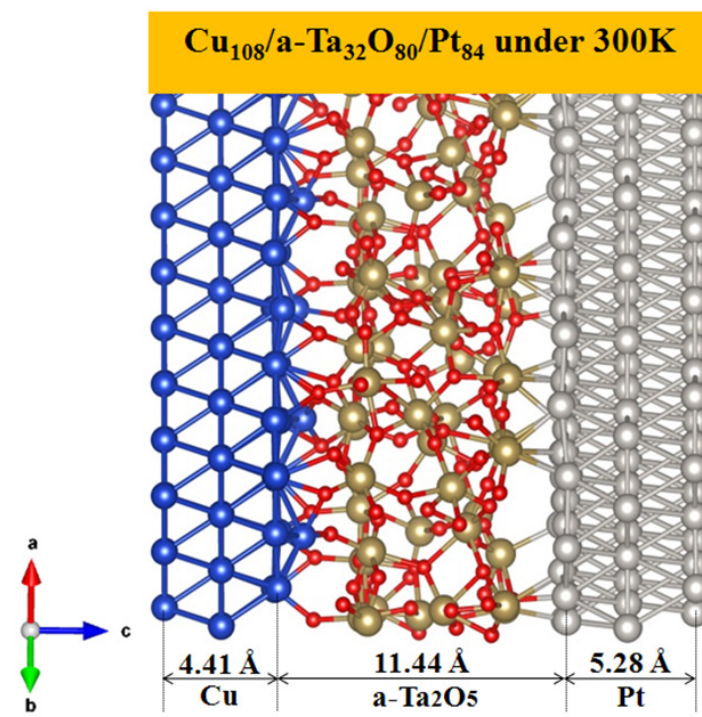
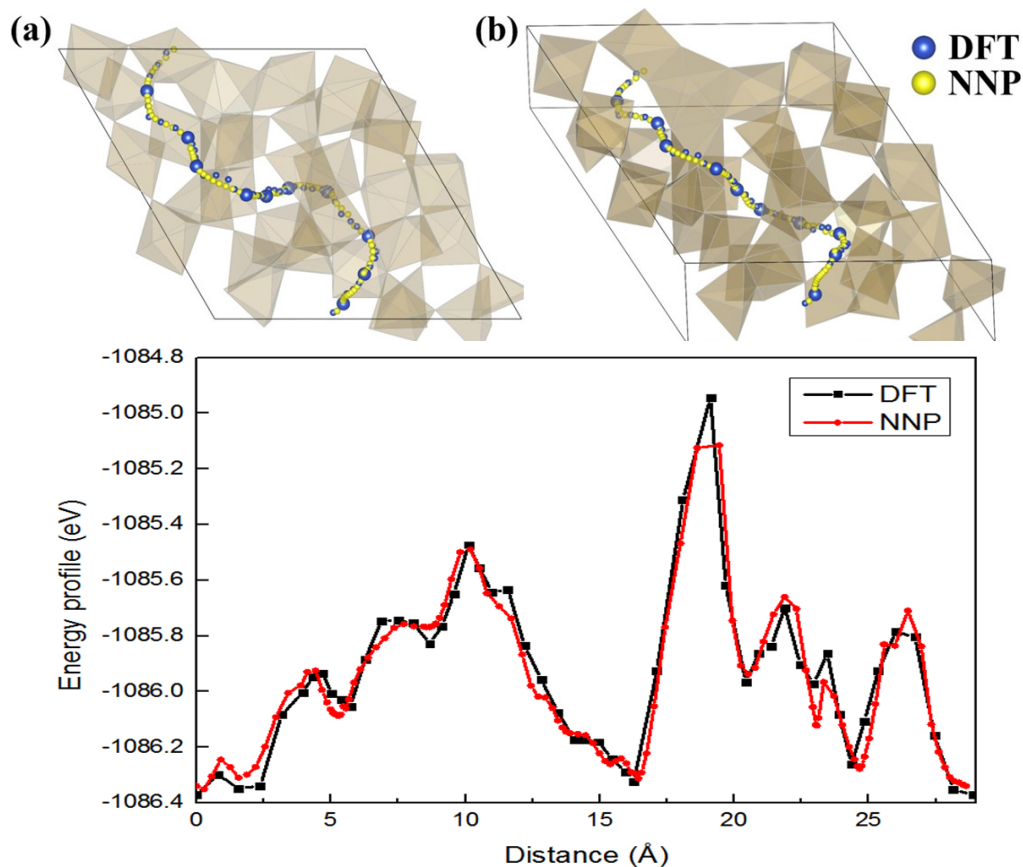
Resistive RAM (ReRAM)

<https://phys.org/news/2013-04-battery-memory-device-future-nanoelectronic.html>

Solid state batteries

# Possible contribution of simulations

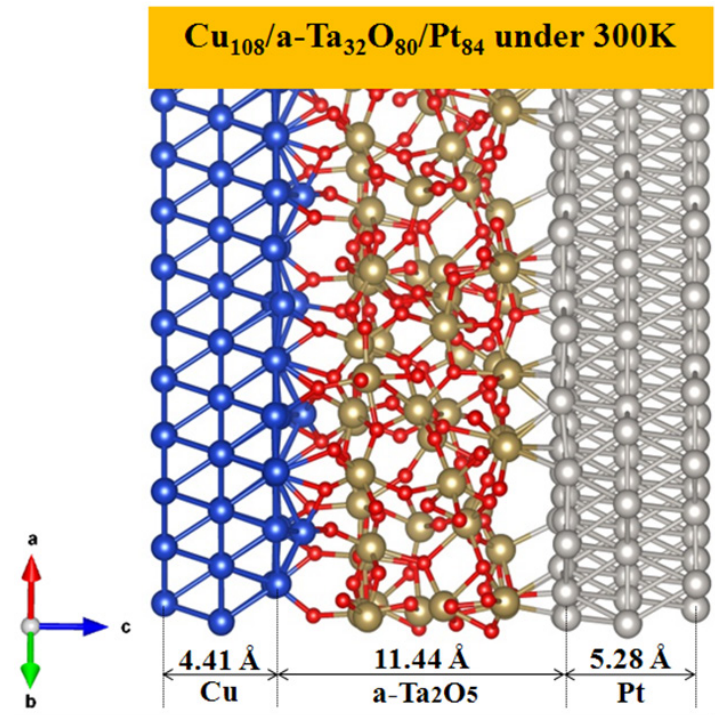
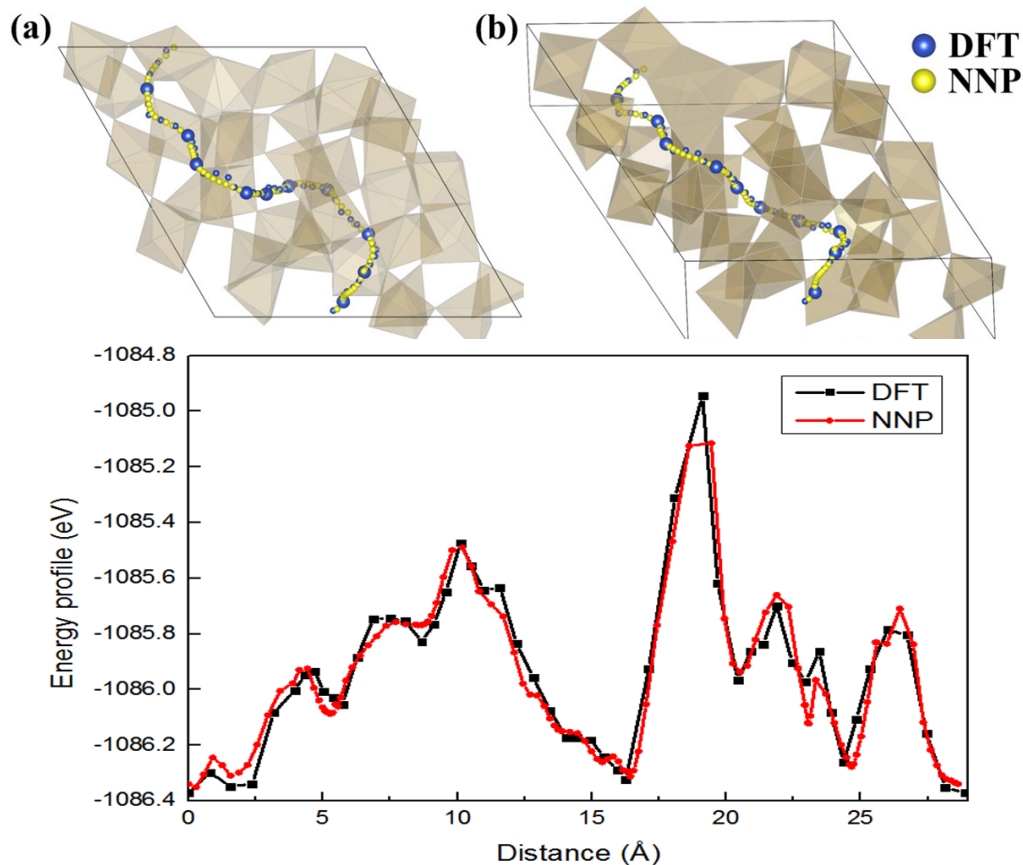
- Material  $\Leftrightarrow$  properties: relation is not straightforward
  - Defects, disorder (amorphous), interfaces...
  - Good descriptors: not yet available
  - Experimental data: often insufficient



Xiao and Watanabe, *ACS Appl. Mater. Interfaces* 7, 519 (2015).

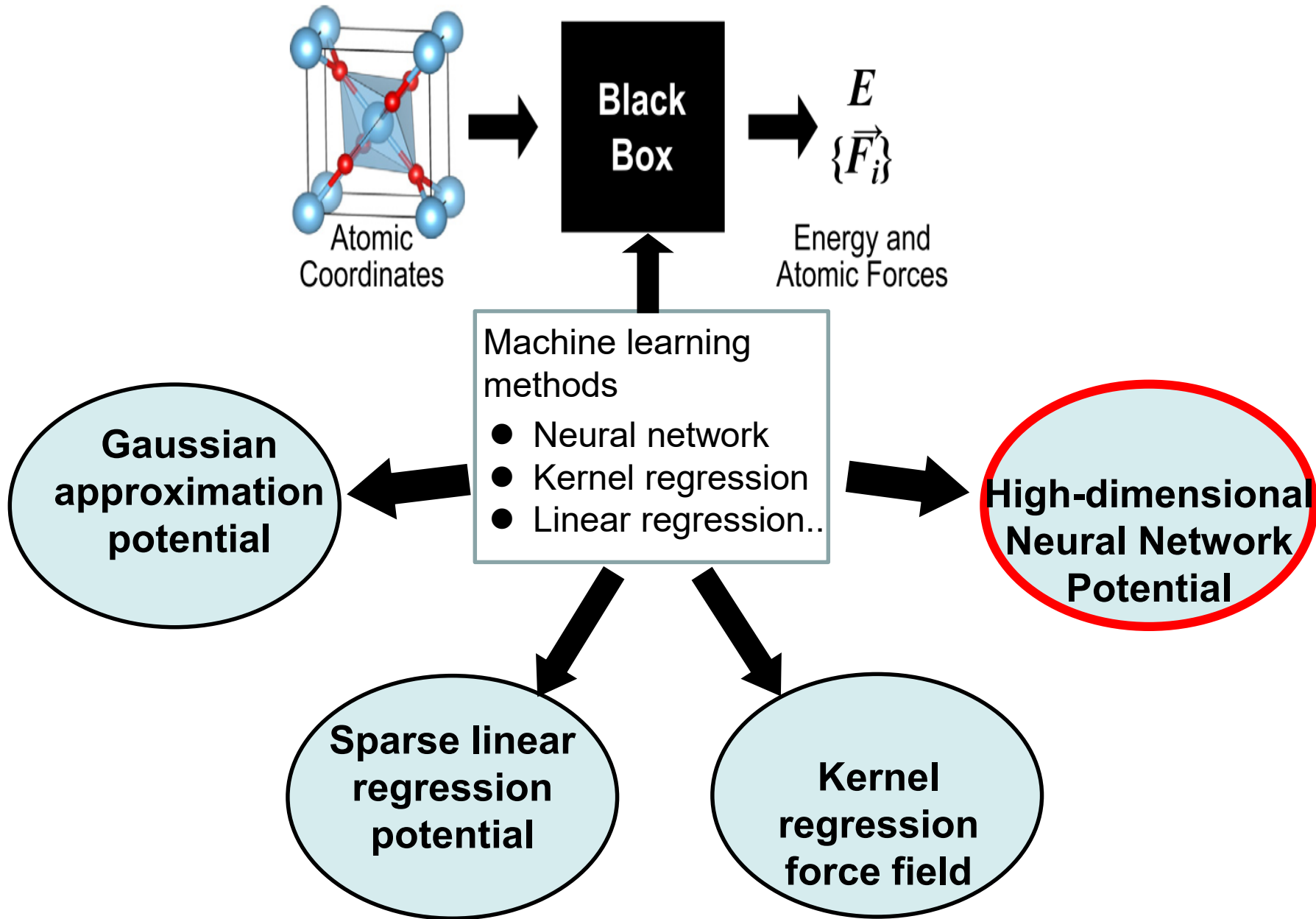
# Conventional approaches of simulations

- First-principles (e.g. density functional theory): reliable, but heavy computation (crucial for amorphous)
- Classical interatomic potential: light computation but not sufficiently reliable

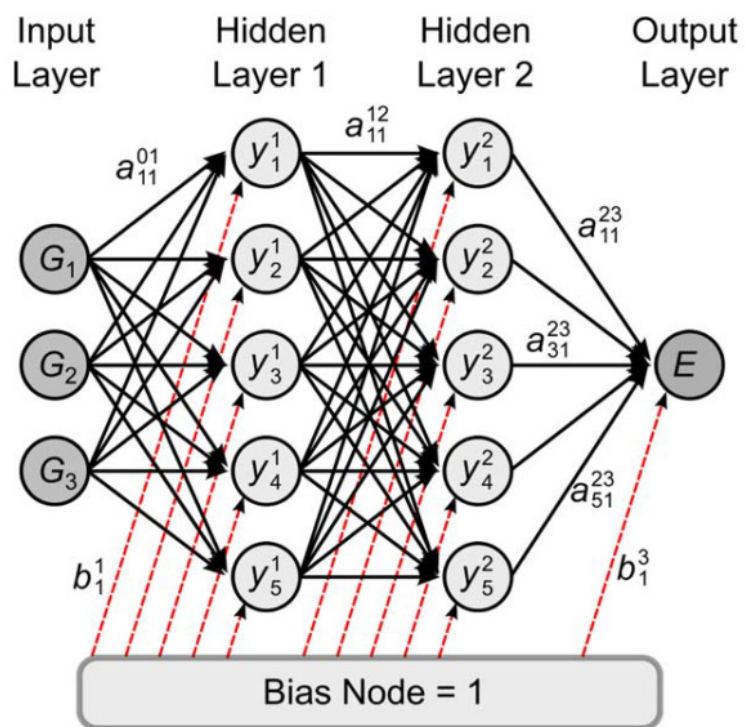


Xiao and Watanabe, *ACS Appl. Mater. Interfaces* 7, 519 (2015).

# Another approach: Machine learning interatomic potential



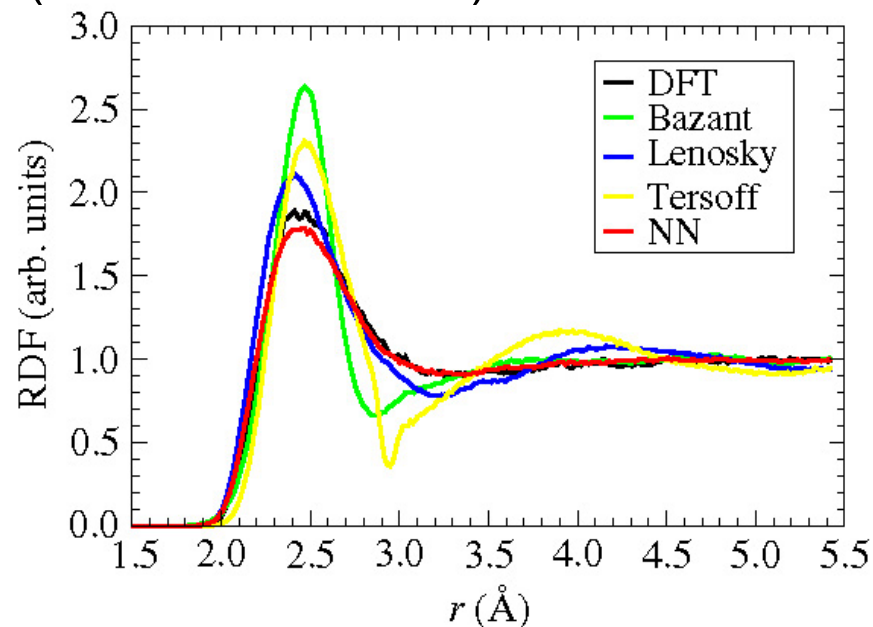
# Interatomic potential constructed with neural network



$$y_i^j = f_i^j \left( b_i^j + \sum_{k=1}^{N_{j-1}} a_{k,i}^{j-1,j} \cdot y_k^{j-1} \right)$$

Behler and Parrinello,  
Phys. Rev. Lett. 98 (2007) 146401.

- Input: information of atomic arrangement
- Output: Energy of the system
- Hidden layers, complex network
  - flexibility of fitting: small error (5 meV/atom for Si)



# Application to Cu migration in Ta<sub>2</sub>O<sub>5</sub>

- The total energy of a structure containing amorphous Ta<sub>2</sub>O<sub>5</sub> matrix and 1 Cu consists of three parts:

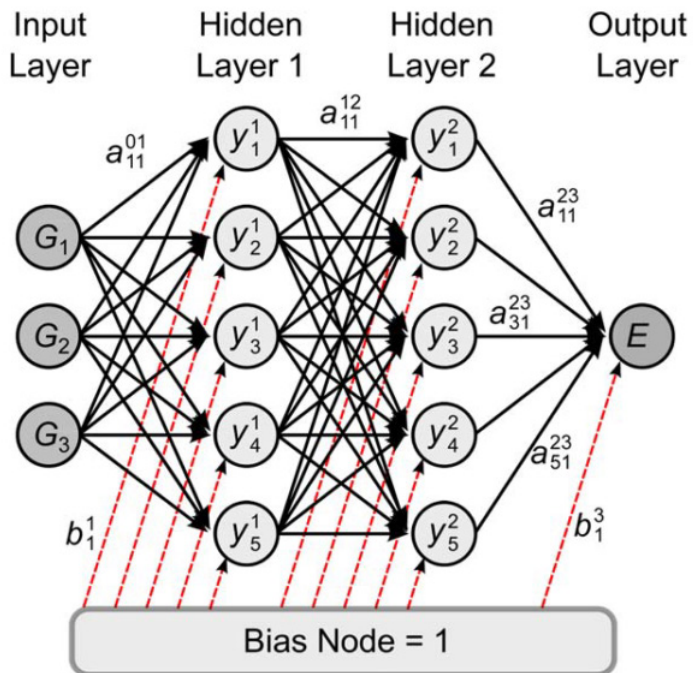
$$E = E_{\text{amorphous}} + E_{\text{Cu}} + E_{\text{relax}}$$

↑  
 Amorphous  
 Ta<sub>2</sub>O<sub>5</sub>

↑  
 Cu  
 insertion

↑  
 Relaxation after  
 Cu insertion

Represented by  
NN potential

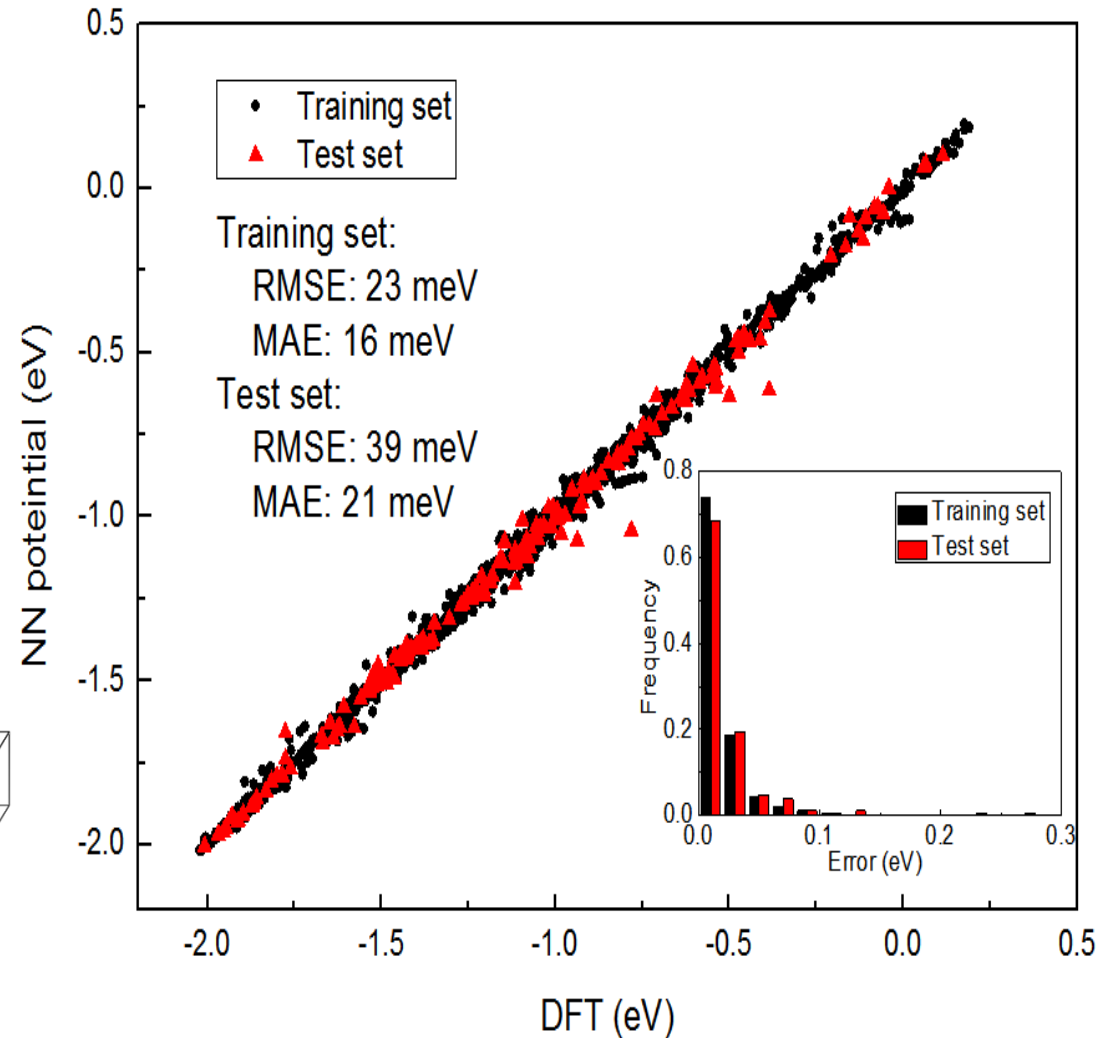
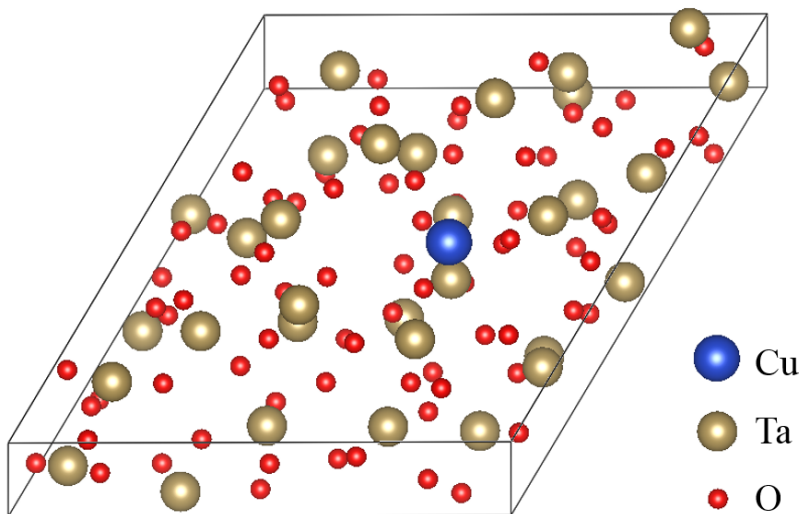


© Ternary system, but only NN potential for Cu is considered

W. Li et al., J. Phys. Soc. Jpn.  
86 (2017) 104004 (Editor's Choice)

# Energy comparison

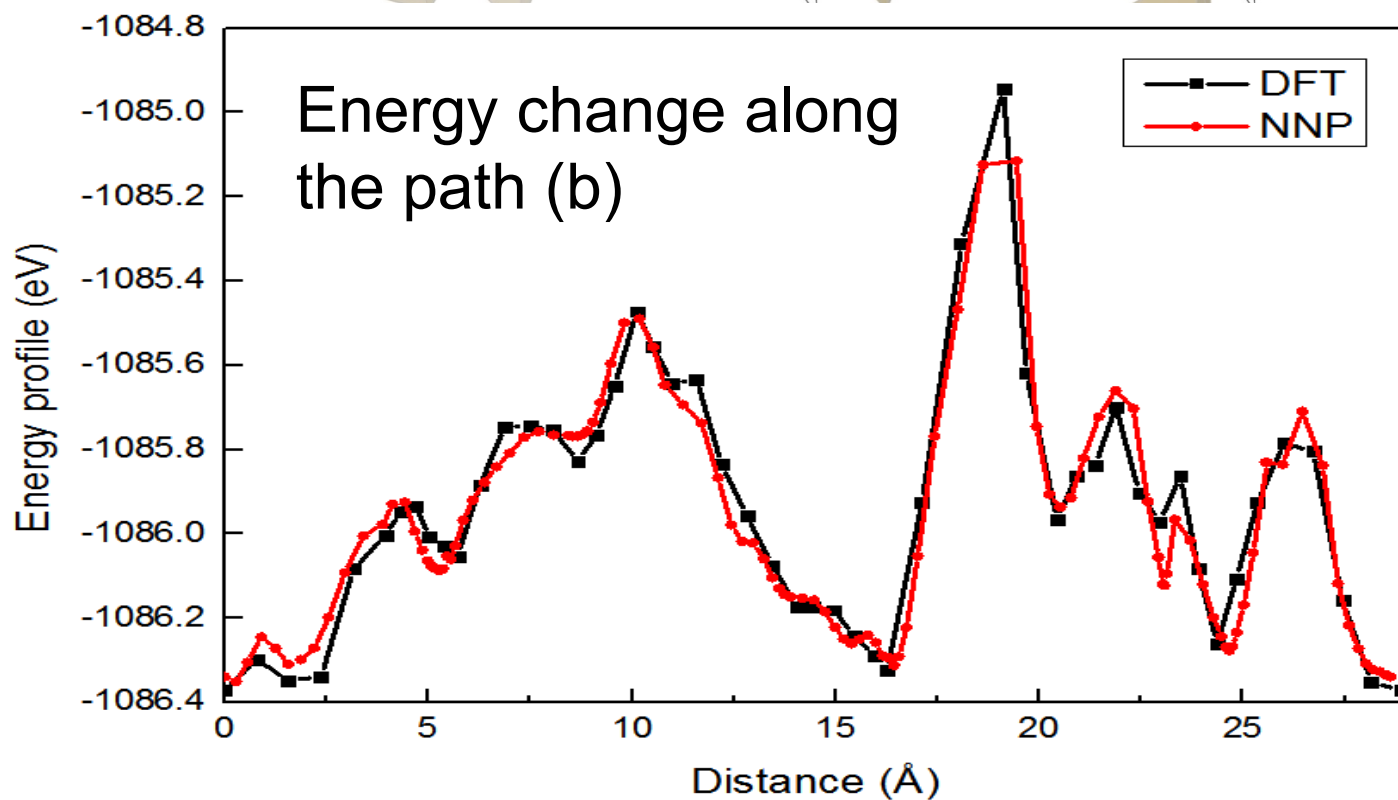
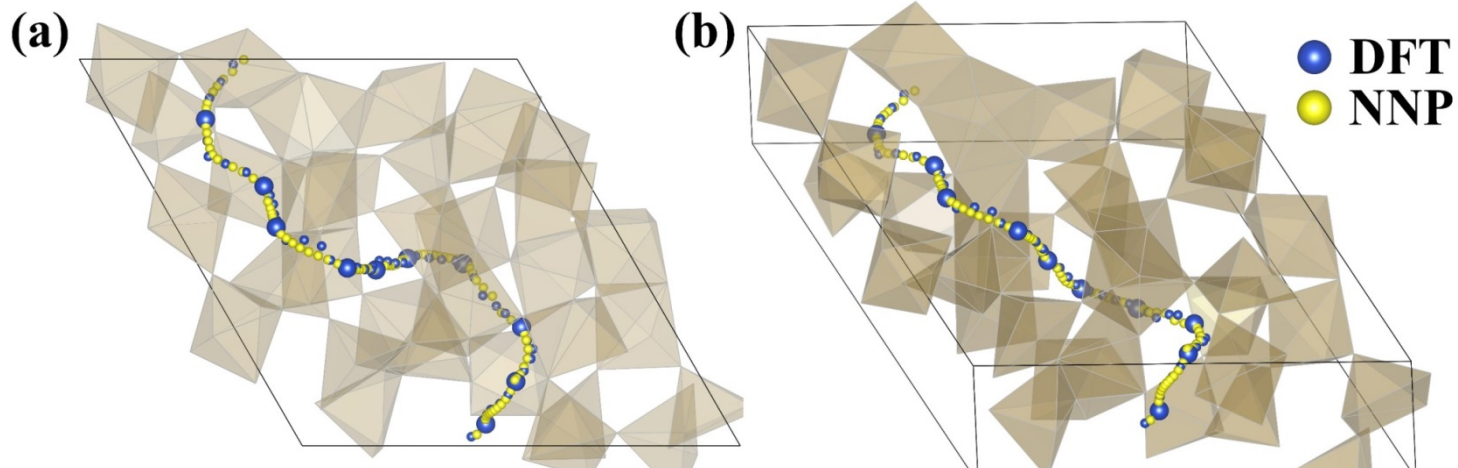
- Density functional theory (DFT) vs. NN potential
- NN potential:  
trained with 1,800 data  
testing data: 200



Li et al., *J. Phys. Soc. Jpn.*  
86, 104004 (2017)

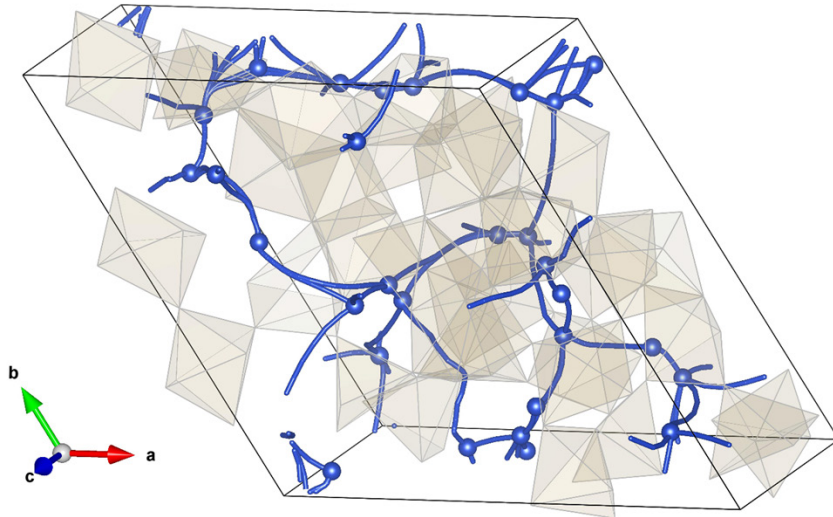


# Diffusion path

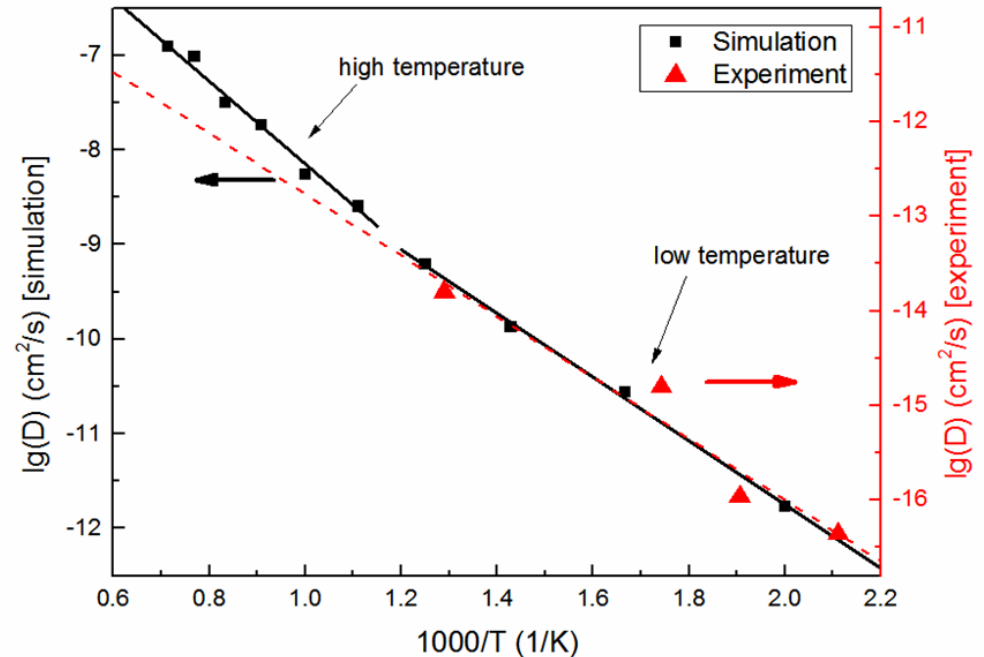
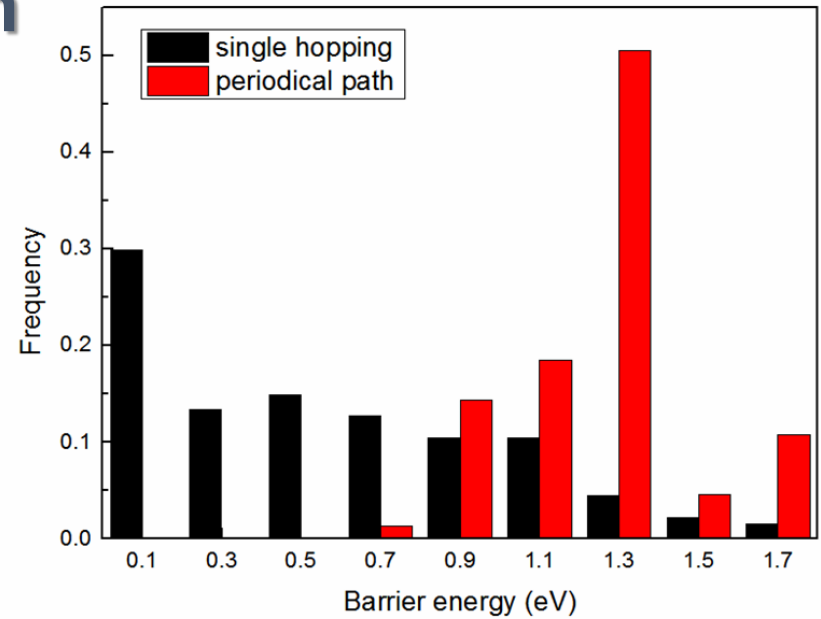


# Barrier energy distribution

periodical path = path connecting a metastable site and the equivalent one in the adjacent super cell



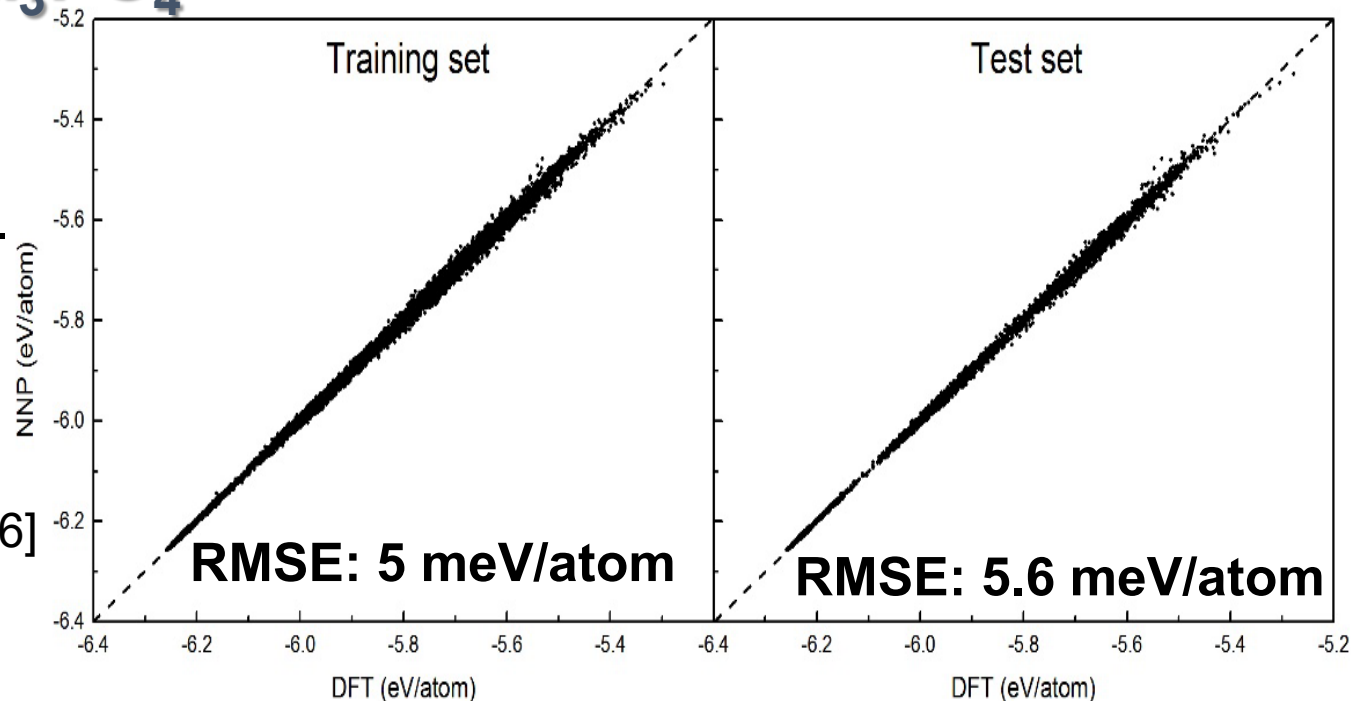
Kinetic Monte Carlo simulation  
Activation energy at low T:  
0.67eV (calc.)  
cf. 0.64eV (exp.)



## Example (2): $\text{Li}_3\text{PO}_4$

- Li, P & O are explicitly considered.
- Training set: 30874
- Testing set: 7718

[W. Li et al., J. Chem. Phys. 147 (2017) 214106]



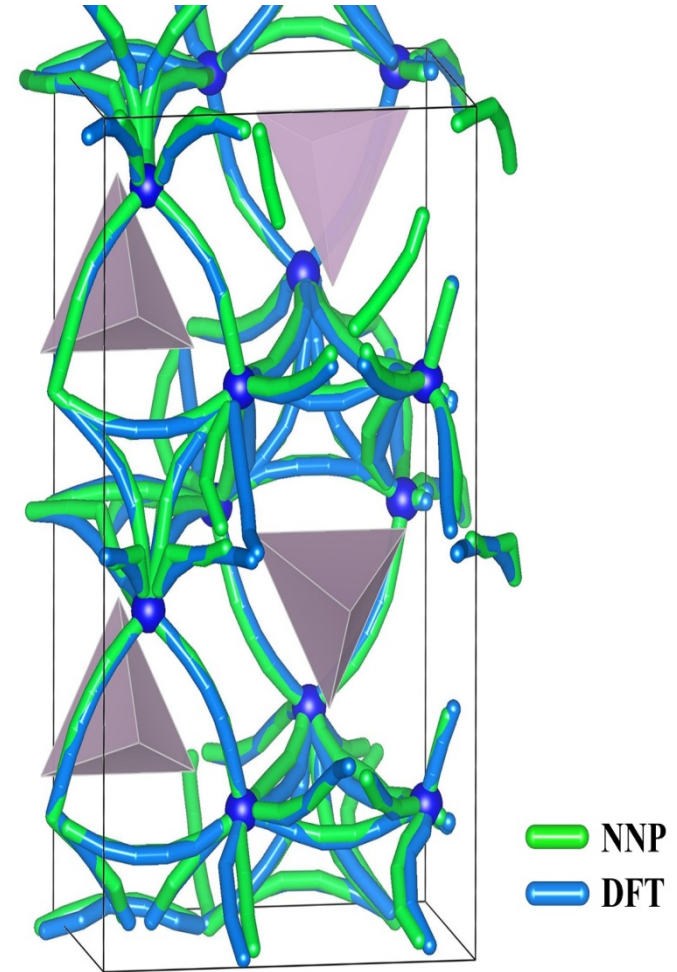
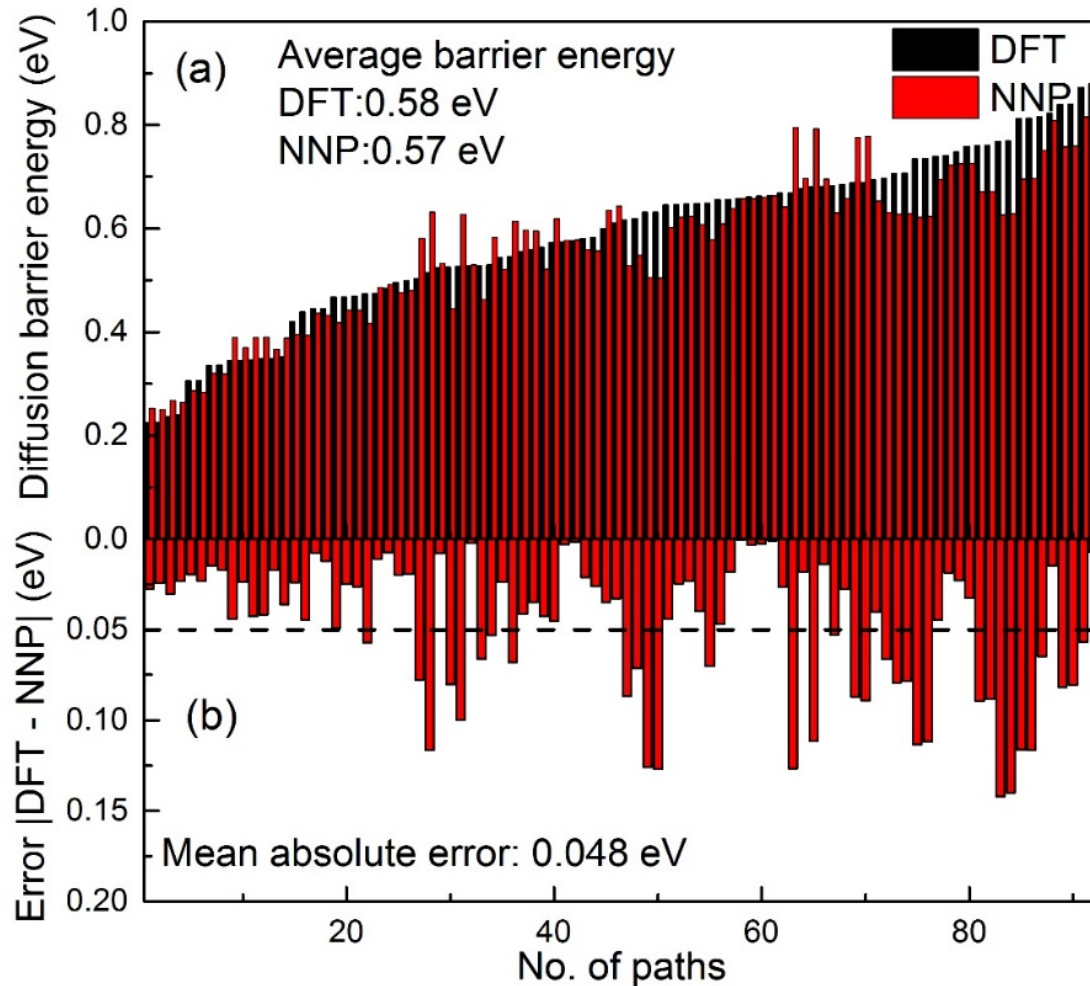
## Properties of $\gamma$ and $\beta$ crystal $\text{Li}_3\text{PO}_4$

	Energy (eV)	NNP Lattice constant ( $\text{\AA}$ )	Energy (eV)	DFT Lattice constant ( $\text{\AA}$ )	Expt. Lattice constant ( $\text{\AA}$ )
$\gamma$ - $\text{Li}_3\text{PO}_4$	-200.96	$a = 5.003$ $b = 6.108$ $c = 10.502$	-200.94	$a = 5.001$ $b = 6.177$ $c = 10.615$	$a = 4.927$ $b = 6.120$ $c = 10.490$
$\beta$ - $\text{Li}_3\text{PO}_4$	-100.49	$a = 4.914$ $b = 5.287$ $c = 6.164$	-100.48	$a = 4.923$ $b = 5.298$ $c = 6.177$	$a = 4.856$ $b = 5.240$ $c = 6.115$

\* O. V. Yakubovich and V. S. Urusov, Crystallogr. Rep. 42, 261 (1997).

# Diffusion paths and barrier energies

- Diffusion paths in  $a\text{-Li}_3\text{PO}_4$



46 diffusion paths in the amorphous  $\text{Li}_3\text{PO}_4$  structure

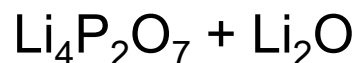
# Transferability to Larger models

From experiment:

[W. Li et al., J. Chem. Phys. 147 (2017) 214106]

1) Partial condensation

reaction

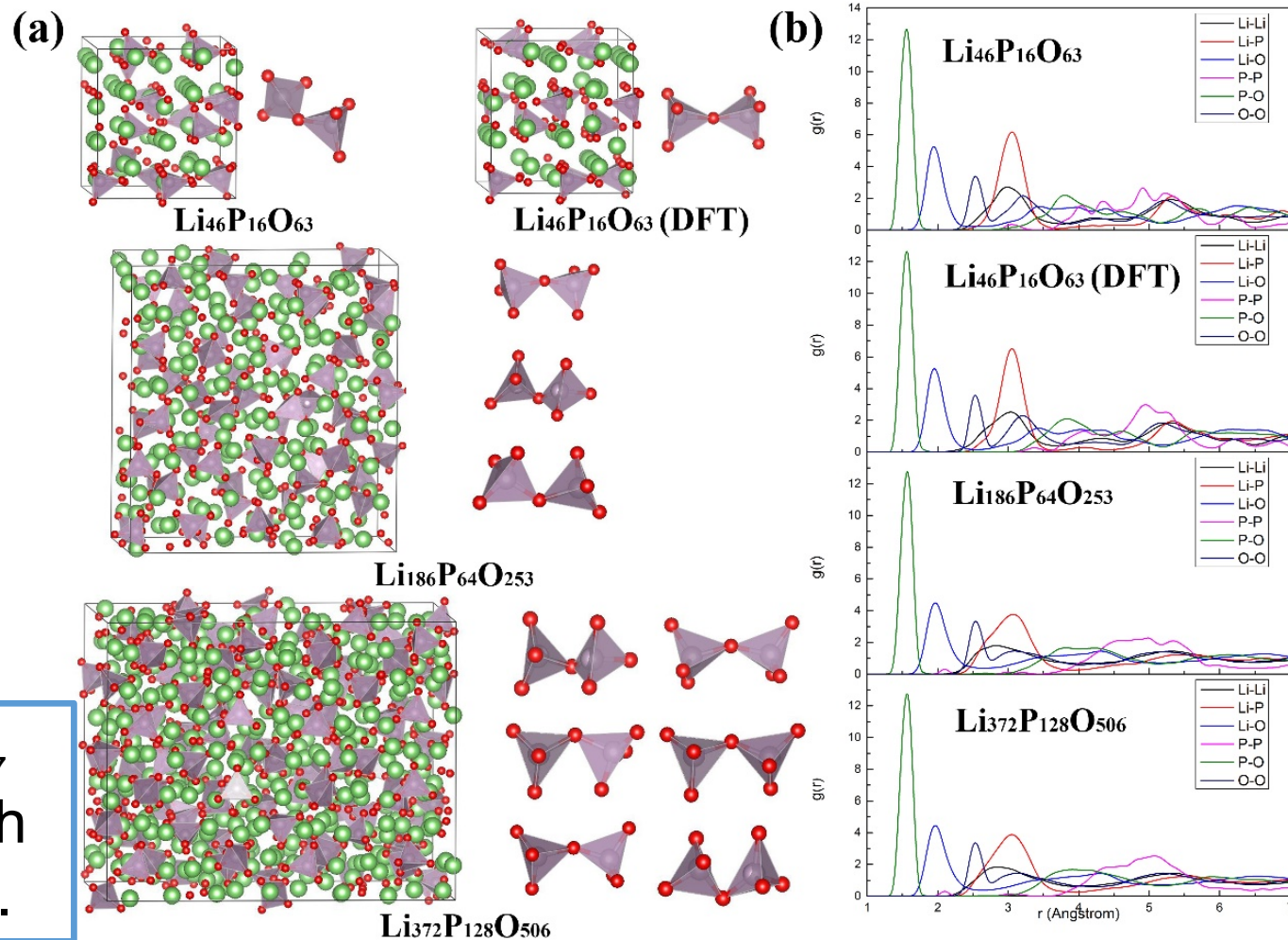


2) Off-stoichiometric

composition

$$\text{Li} : \text{P} = 2.9$$

Existence of  $\text{P}_2\text{O}_7$  dimer agree with NMR observation.

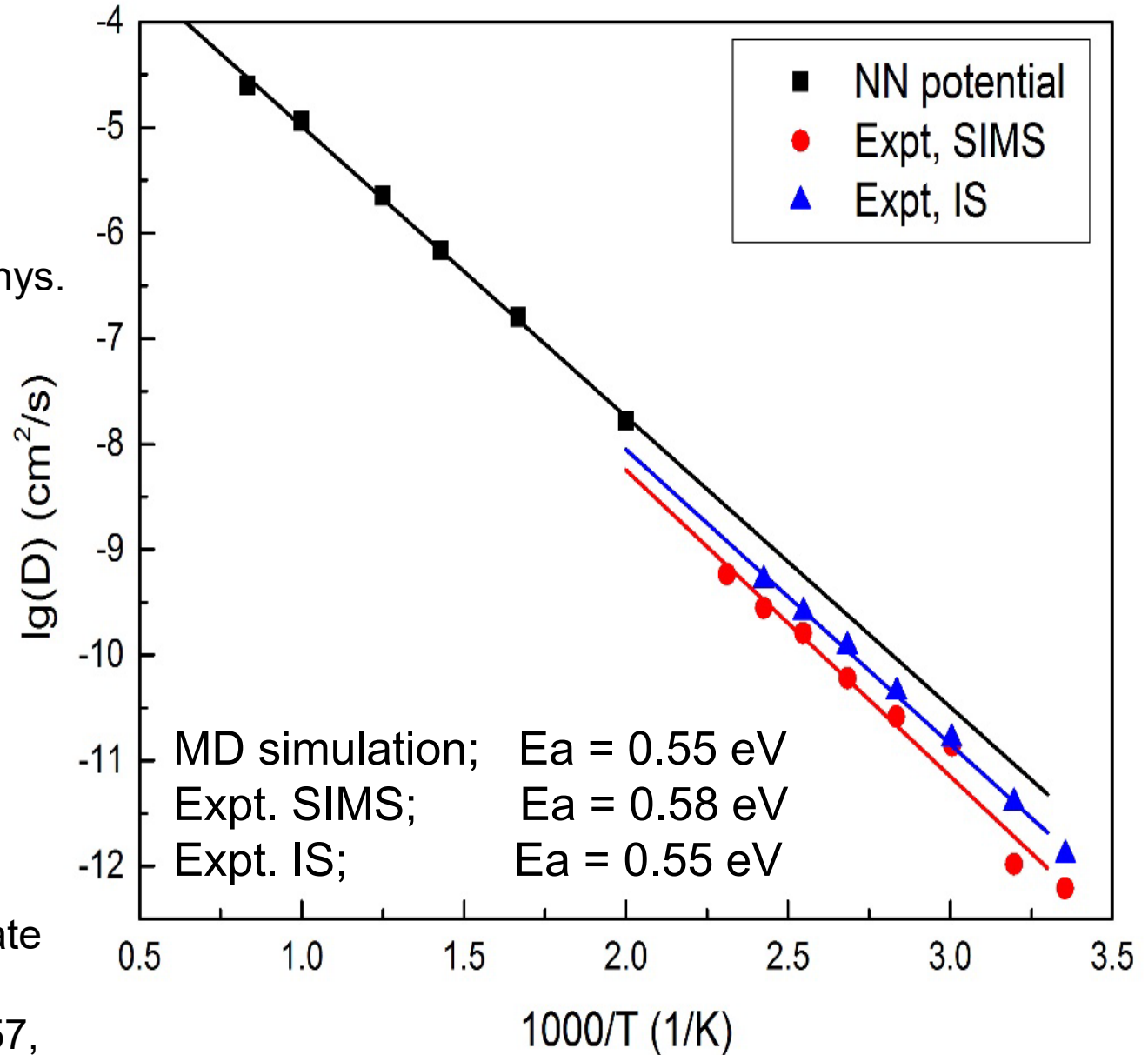


# Diffusion coefficients

Calculated with  
the largest model

[W. Li et al., J. Chem. Phys.  
147 (2017) 214106]

Exp:  
Kuwata, et. al, Solid State  
Ionics 294, 59 (2016);  
J. Electrochem. Soc. 157,  
A521 (2010).



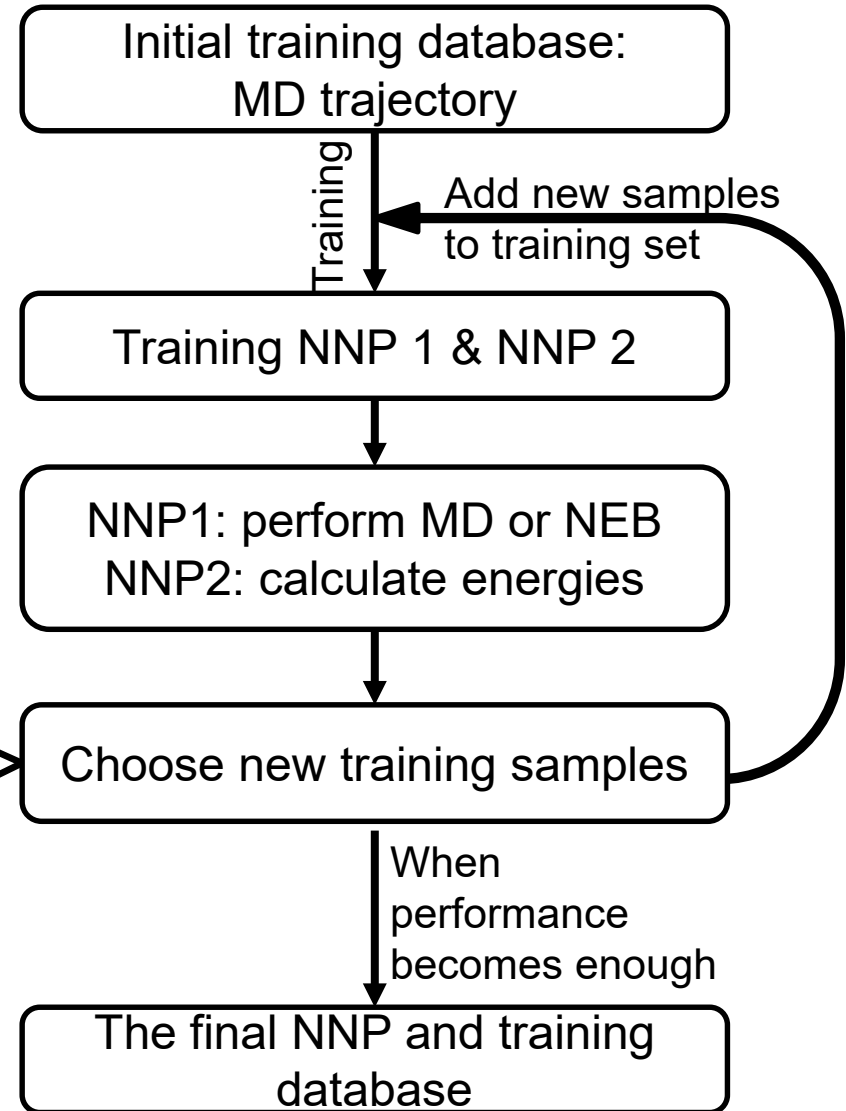
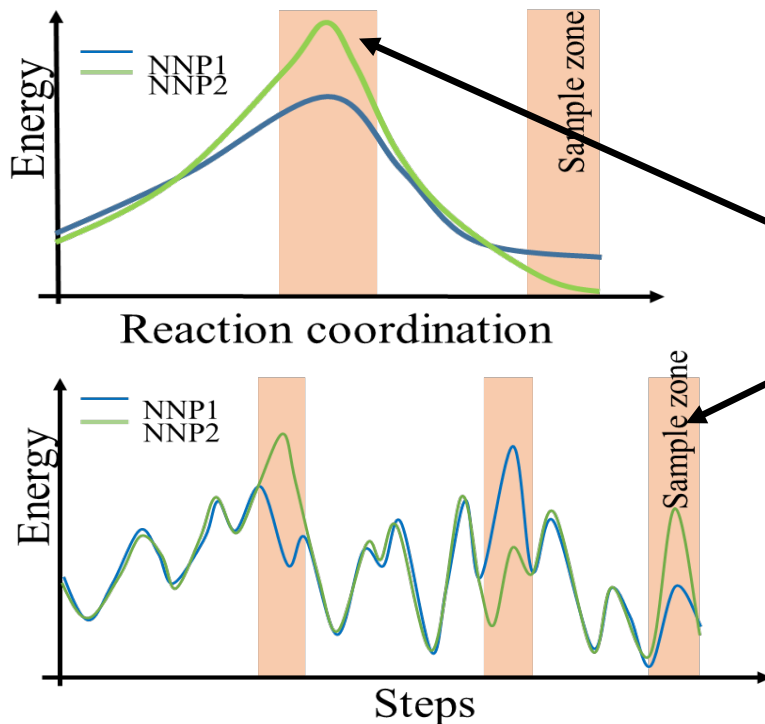
# Example (3): Cu in Al<sub>2</sub>O<sub>3</sub>

[W. Li, Doctoral thesis]

- NN potential applicable to composition/density variation

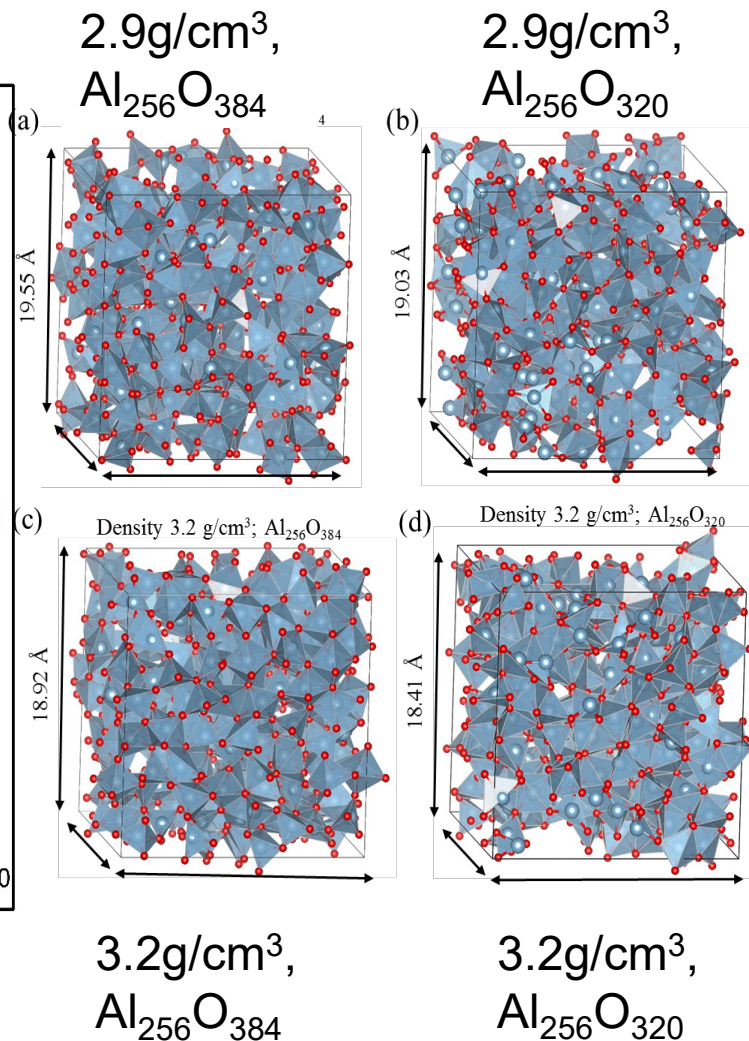
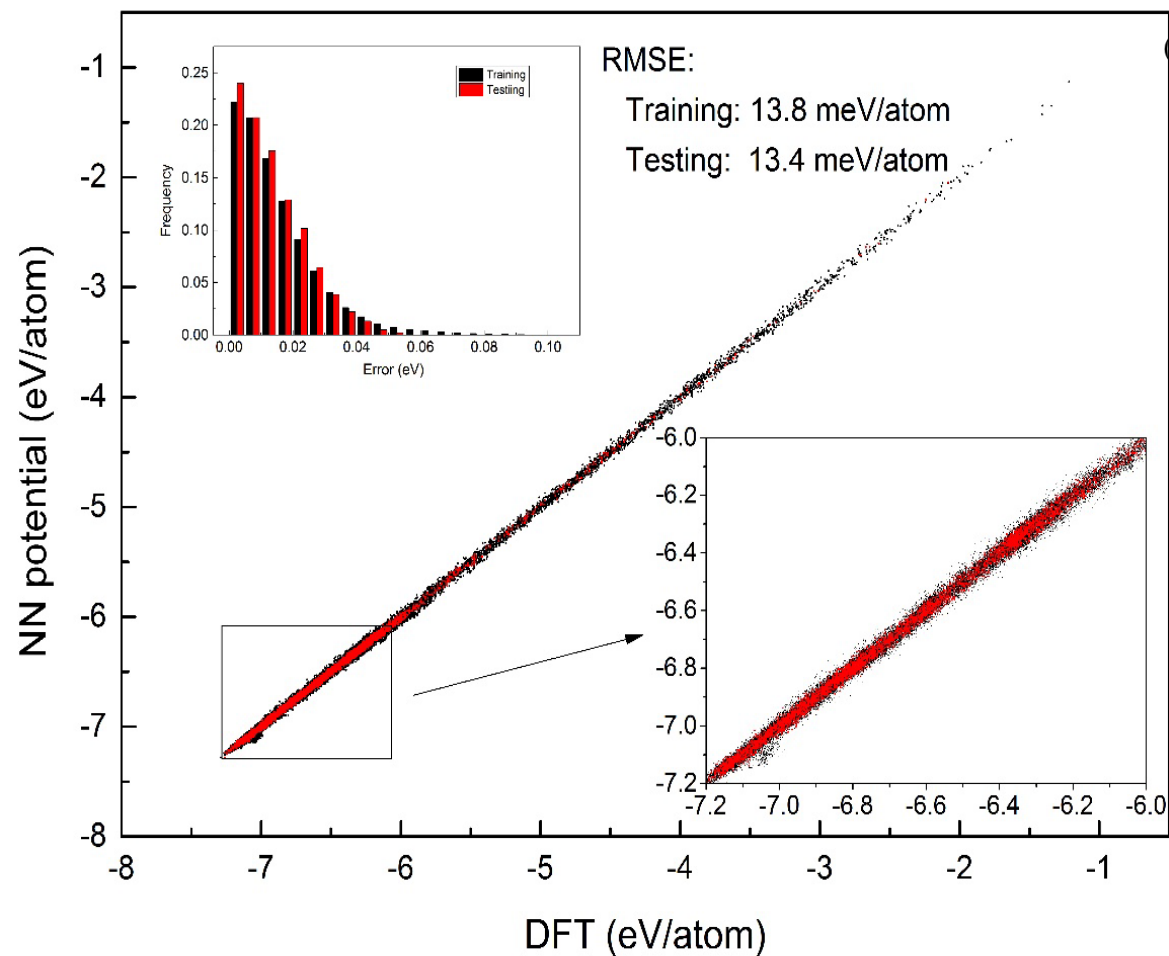
**Total number: 41495**

- Number of atoms: < 161 atoms
- Density: 2.9 ~ 3.2 g/cm<sup>3</sup>
- Al/O ratio: 1 ~ 1.5



# Energy prediction

[W. Li, Doctoral thesis]





# Diffusion coefficients & activation energies:

dependence on composition & density

Stoichiometric case

Density = 2.9 g/cm<sup>3</sup>

# Summary

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Interatomic potentials constructed using neural network and first-principles simulation data to examine atomic diffusion behaviors in amorphous materials

- Cu in  $\text{Ta}_2\text{O}_5$ : simplified method (considering only Cu explicitly)
- Li in  $\text{Li}_3\text{PO}_4$ : transferability to much larger models than those used in training
- Cu in  $\text{Al}_2\text{O}_3$ : considering composition and density variation

Having both reliability and computational efficiency: promising!

## Future plans

- ✓ Improvements (under electric fields, data sampling method, large-scale MD)
- ✓ Defects (in GaN etc.) and interfaces (Au/ $\text{Li}_3\text{PO}_4$  etc.)
- ✓ Phonon & thermal transport
- ✓ Ferroelectric materials (long-range Coulomb interaction)